**PATENT** CR00-029

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Application Date Filed: Title:

Serial No.

DEC 1 5 2003

Date Fil	tion No.:	Talin et al. 10/024164 18 December 2001	Group Art Unit: 2879 Examiner: unknown
Title:		FED CATHODE ST METHOD OF FAB	RUCTURE USING ELECTROPHORETIC DEPOSITION AND RICATION
	<del>-</del>		CERTIFICATE OF MAILING
	POSTAI ASSIST		Date of Deposit
		Shell and	MOTOROLA INC. Name of Assignee
	Sic	SNATURE )	<u>12-11-03</u> DATE
		INFORMATIO	N DISCLOSURE STATEMENT (IDS)
	t Commissionston, D.C. 2	oner For Patents 0231	
	n attached .		56 and in compliance with 37 C.F.R. §§1.97 and 1.98, the references or subsequently identified herein, are being submitted herewith for a Trademark Office.
I.	COPIES		
	ca		U.S. and foreign patents; (ii) each publication or that portion which (iii) all other information or that portion which caused it to be listed, is
	b. Ar	ny patents, publications closed herewith were p	or other information which are listed on PTO/SB/08 which are not reviously cited by or submitted to the PTO in one of the following n relied upon for an earlier filing date under 35 U.S.C. §120:
	<u>U</u> .	S. Serial Number	U.S. Filing Date
II.	a. \( \bar{\bar{\bar{\bar{\bar{\bar{\bar{	ccept as may be indicate formation are in the Eng concise explanation of not in the English langu	HE RELEVANCE (check at least one box)  and below in (b) of this section, all of the patents, publications or other ish language (concise explanation not required). The relevance of all patents, publications or other information listed that age is as follows:  Information is provided for the Examiner's consideration:
III. 🗆	CROSS RE The Exami- related to	FERENCE TO RELAT ner is advised that the fo the present application	-

Art Unit

Filing Date

## **FEES**

IV. 🖾	THIS III a. □ b. □ c. ☑ d. □	os is being filed under 37 C.F.R. §1.97(b): (check one box) within three months of the filing date of a national application other than a continued prosecution application under § 1.53(d) (37 C.F.R. §1.97(b)(1)). No fee or statement is required. within three months of the date of entry of the national stage as set forth in § 1.491 in an international application (37 C.F.R. §1.97(b)(2)). No fee or statement is required. before the mailing date of a first Office Action on the merits (37 C.F.R. §1.97(b)(3)). No fee or statement is required. before the mailing date of a first Office Action after the filing of a request for continued examination under § 1.114 (37 C.F.R. § 1.97(b)(4)). No fee or statement is required.
v. 🗖	before t	OS IS BEING FILED UNDER 37 C.F.R. §1.97(c): (check one box) the mailing date of any of a Final Office Action under 37 C.F.R. §1.113, a Notice of Allowance of C.F.R. §1.311, or an action that otherwise closes prosecution in the application (See 37 C.F.R. of O.F.R. §1.311, or an action that otherwise closes prosecution in the application (See 37 C.F.R. of O.F.R. §1.17(p).  No statement; therefore, charge deposit account 502117the fee set forth in 37 C.F.R. §1.17(p). See the statement below. No fee is required.
VI. 🗌		OS IS BEING FILED UNDER 37 C.F.R. §1.97(d): fore payment of the issue fee and is accompanied by the following: a statement under 37 C.F.R. §1.97(e) as provided below; and charge deposit account 502117 the petition fee set forth in §1.17(p).
VII. 🗌		MENT UNDER 37 C.F.R. §1.97(e) (check only one box, if applicable) ersigned hereby states that each item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application not more than three months prior to the filing of IDS or
•	b. 🗌	no item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application, and to knowledge of the person signing the statement after making reasonable inquiry, no item of information contained in the IDS was known to any individual designated in 37 C.F.R. 1.56(c) more than three months prior to the filing of this statement, or
	c.	some of the items of information contained in the IDS were cited in a communication from a foreign Patent Office. As to this information, the undersigned states that each item of information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application not more than three months prior to the filing of this IDS. As to the remaining information, the undersigned hereby states that no item of this remaining information contained in the IDS was cited in a communication from a foreign Patent Office in a counterpart foreign application or, to the knowledge of the person signing the statement after making reasonable inquiry, no item of information contained in the IDS was known to any individual designated in 37 C.F.R. 1.56(c) more than three months prior to the filing of this statement.
VIII.	PAYME	A check in the amount of is enclosed for the above-identified fee(s).  Please charge Deposit Account No. 502117 in the amount of \$180.00 for the above-indicated fee(s).
		If Applicant has overlooked any additional fees, or if any overpayment has been made, the Commissioner is hereby authorized to credit or debit Deposit Account 502117.  Two Copies of this paper are attached for Deposit Account charges and debits.

The above references are being cited only in the interests of candor and without any admission that they constitute statutory prior art or contain matter which anticipates the invention or which would render the same obvious, either singly or in a combination, to a person of ordinary skill in the art.

## PATENT CR00-029

If the Examiner has any questions concerning this IDS, he/she is requested to contact the undersigned. If it is determined that this IDS has been filed under the wrong rule, the PTO is requested to consider this IDS under the proper rule (with a petition if necessary) and charge the appropriate fee to Deposit Account No. 502117

Respectfully submitted,

Talin et al.

MOTOROLA, INC. Customer Number 23330 William E. Koch Attorney for Applicant(s) Reg. No. 29,659

Tel. 602-952-3486

Enclosures:

PTO/SB/08
References

Foreign Search Report

Other:

OIPE VOIS

ease type a plus sign (+) inside this box.

Substitute for form 1449A/PTO				Complete if Known				
7				Application Number	10/024164			
INFORMATION DISCLOSURE				Filing Date	18 December 2001			
STATEMENT BY APPLICANT				First Named Inventor	Talin et al.			
				Group Art Unit	2879			
(use as many sheets as necessary)				Examiner Name				
Sheet	1	of	4	Attorney Docket Number	CR00-29			

			U. S. PATENT DOCUMEN		
Examiner Initials*	Cite No.	U.S. Patent Documen  Number Kind Code <sup>2</sup> (if known)	Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	1	5872422	Xu et al.	2/16/99	
	2	5773921	Keesmann et al.	6/30/98	
	3	6514113 B1	Lee et al.	2/4/03	
	1				
-					
					<u>-</u>
	<del> </del>			<u> </u>	
	<u> </u>				
				,	
	ļ				
	<del>                                     </del>				

			FORE	IGN P	ATENT DOCUMENT	`S		
Examiner Initials*	Cite No.	Foreign Patent Document  Office <sup>3</sup> Number <sup>4</sup> Kind Code <sup>2</sup> (if known)		Name of Patentee or Applicant of Cited Document	Date of Publication of Cited Document MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T 6	
								L
	<u> </u>							L
								L
								╁

Examiner	 Date	
Signature	Considered	

<sup>&</sup>lt;sup>1</sup> Unique citation designation number. <sup>2</sup> See Kinds of U.S. Patent Documents. <sup>3</sup> Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). <sup>4</sup> For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. <sup>5</sup> Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. <sup>6</sup> Applicant is to place a check mark here if English Language Translation is attached.

DEC 7 5 2003

Rease type a plus sign (+) inside this box.

Substitute for form 1449A/PTO

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

4

(use as many sheets as necessary)
Sheet 2

Complete if Known					
Application Number	10/024164				
Filing Date	18 December 2001				
First Named Inventor	Talin et al.				
Group Art Unit	2879				
Examiner Name					
Attorney Docket Number	CR00-029				

		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T 2
	4	Xu et al., "A method for fabricating large-area, patterned, carbon nanotube field emitters," Applied Physics Letters, Vol. 74, No. 17, 26 April 1999, pp. 2549-2551.	
	5	Fan et al., "Self-oriented regular arrays of carbon nanotubes and their field emission properties," Science, Vol. 283, 22 January 1999, pp. 512-514.	
	6	Suh et al, "Highly ordered two-dimensional carbon nanotube arrays," Applied Physics Letters, Vol. 75, No. 14, 4 October 1999, pp. 2047-2049.	
	7	Hernadi et al. "Catalytic synthesis of carbon nanotubes using zeolite support," Zeolites 17, 1996, pp. 416-423.	
	8	Murakami et al., "Field emission from well-aligned, patterned, carbon nanotube emitters," Applied Physics Letters, Vol. 76, No. 13, 27 March 2000, pp. 1776-1778.	
	9	Ma et al., "Polymerized carbon nanobells and their field-emission properties," Applied Physics Letters, Vol. 75, No. 20, 15 November 1999, pp. 3105-3107.	
	10	Li et al, "Highly-ordered carbon nanotube arrays for electronics applications," Applied Physics Letters, Vol. 75, No. 3, 19 July 1999, pp. 367-369.	
.=	11	Terrones et al., "Controlled production of aligned-nanotube bundles," Nature, Vol. 388, 3 July 1997, pp.52-55.	
	12	Xu et al., "Controlling growth and field emission property of aligned carbon nanotubes on porous silicon substrates," Applied Physics Letters, Vol. 75, No. 4, 26 July 1999, pp. 481-483.	
	13	Tsai et al., "Bias-enchanced nucleation and growth of the aligned carbon nanotubes with open ends under microwave plasma synthesis," Applied Physics Letters, Vol. 24, No. 23, 7 June 1999, pp. 3462-3464.	
	14	Kind et al., "Patterned films of nanotubes using microcontact printing of catalysts," Advanced Materials, 11, No. 15, 1999, pp. 1285-1289.	

Examiner	Date	
Signature	Considered	

<sup>&</sup>lt;sup>1</sup> Unique citation designation number. <sup>2</sup> Applicant is to place a check mark here if English Language Translation is attached.

Please type a plus sign (+) inside this box

Substitute	for form 1449A/PTO	)			Complete if Known		
				Application Number	10/024164		
INFORM	MATION DISC	LOSURE		Filing Date	18 December 2001		
STATE	STATEMENT BY APPLICANT			First Named Inventor	Talin et al.		
				Group Art Unit	2879		
(use as many sheets as necessary)				Examiner Name			
Sheet	3	Of	4	Attorney Docket Number	CR00-029		

		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T
	15	Nilsson et al., "Scanning field emission from patterned carbon nanotube films." Applied Physics Letters, Vol. 76. No. 15, 10 April 2000, pp. 2071-2073.	į
·	16	Kuttel et al, "Electron field emission from phase pure nanotube films grown in a methane/hydrogen plasma," Applied Physics Letters, Vol. 73, No. 15, 12 October 1998, pp. 2113-2115.	
	17	Ren et al., "Synthesis of large arrays of well-aligned carbon nanotubes on glass," Science, Vol. 282 6 November 1998, pp. 1105-1107.	
	18	Ren et al. "Growth of a single freestanding multiwall carbon nanotube on each nanonickel dot," Applied Physics Letters, Vol 75, No. 8 23 August 1999, pp. 1086-1088.	
	19	Pan et al., "Very long carbon nanotubes," Nature, Vol. 394, 13 August 1998, pp. 631-632.	
	20	Zhang et al., "A flat panel display device fabricated by using carbon nanotubes cathode," IEEE, 2001, pp. 193-194.	
	21	Zhong et al., "Large-scale well aligned carbon nitride nanotube films: Low temperature growth and electron field emission," Journal of Applied Physics, Vol. 89, No. 11, 1 June 2001, pp. 5939-5943.	
	22	Kim et al., "Growth and field emission of carbon nanotubes on electroplated Ni catalyst coated on glass substrates," Journal of Applied Physics, Vol. 90, 1 September 2001, pp.2591-2594.	
	23	Gulyaev et al., "Field emitter arrays on nanotube carbon structure films," J. Vac.Sci. Technol. B 13(2), Mar/Apr 1995, pp. 435-436.	<del> </del>
	24	Chernozatonskii, et al. "Nanotube carbon structure tips – a source of high field emission of electrons," Mat. Res.Soc. Symp. Proc., Vol. 359. 1995 Materials Research Society, pp. 99-104.	
	25 -	Su et al., "A scalable CVD method for the synthesis of single-walled carbon nanotubes with high catalyst productivity," Chemical Physics Letters 322, (2000), pp 321-326.	

Examiner	Date	
Signature	Considered	

<sup>&</sup>lt;sup>1</sup> Unique citation designation number. <sup>2</sup> Applicant is to place a check mark here if English Language Translation is attached.

DEC 1 5 2003 P

2003 Please type a plus sign (+) inside this box.

Apstitute for form 1449A/PTO INFORMATION DISCLOSURE				Complete if Known		
				Application Number	10/024164	
STATEMENT BY APPLICANT  (use as many sheets as necessary)				Filing Date	18 December 2001	
				First Named Inventor	Talin et al.	
				Group Art Unit	2879	
				Examiner Name		
Sheet	4	of	4	Attorney Docket Number	CR00-029	

		OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS	
Examiner Initials*	Cite No. 1	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T
	26	Li et al. "Large-scale synthesis of aligned carbon nanotubes," Science, Vol. 274, 6 December 1996, pp. 1701-1703	
	27	Cassell et al. "Large scale CVD synthesis of single-walled carbon nanotubes," J. Phys. Chem. B. 1999, 103, pp. 6484-6492.	
	28	Cassell et al. "Directed growth of free-standing single walled carbon nanotubes," J. Am. Chem. Soc. 1999, 121, pp. 7975-7976.	
	.29	Cassell et al, "Combinatorial optimization of heterogeneous catalysts used in the growth of carbon nanotubes," Langmuir 2001, 17, pp. 260-264.	
	30	Li et al, "Large-scale synthesis of aligned carbon nanotubes," Science, Vol. 274, 6 December 1996, pp. 1701-1703.	
,			
		÷	

Examiner	Date		_
Signature	Consid	lered	

<sup>&</sup>lt;sup>1</sup> Unique citation designation number. <sup>2</sup> Applicant is to place a check mark here if English Language Translation is attached.